Single pole double throw (SPDT) switch SA630

DESCRIPTION

The SA630 is a wideband RF switch fabricated in BiCMOS technology and incorporating on-chip CMOS/TTL compatible drivers. Its primary function is to switch signals in the frequency range DC - 1GHz from one 50Ω channel to another. The switch is activated by a CMOS/TTL compatible signal applied to the enable channel 1 pin (ENCH1).

The extremely low current consumption makes the SA630 ideal for portable applications. The excellent isolation and low loss makes this a suitable replacement for PIN diodes.

The SA630 is available in an 8-pin dual in-line plastic package and an 8-pin SO (surface mounted miniature) package.

FEATURES

- Wideband (DC - 1GHz)
- Low through loss (1dB typical at 200MHz)
- Unused input is terminated internally in 50Ω
- Excellent overload capability (1dB gain compression point +18dBm at 300MHz)
- Low DC power (170μA from 5V supply)
- Fast switching (20ns typical)
- Good isolation (off channel isolation 60dB at 100MHz)

PIN CONFIGURATION

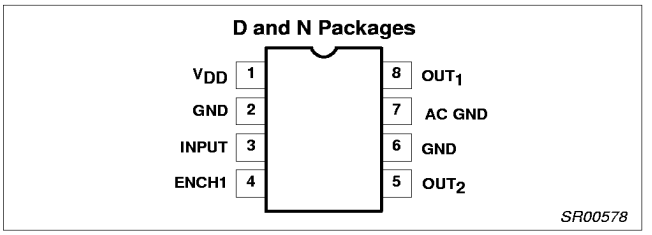


Figure 1. Pin Configuration

- Low distortion (IP_3 intercept +33dBm)
- Good 50Ω match (return loss 18dB at 400MHz)
- Full ESD protection
- Bidirectional operation

APPLICATIONS

- Digital transceiver front-end switch
- Antenna switch
- Filter selection
- Video switch
- FSK transmitter

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
8-Pin Plastic Dual In-Line Package (DIP)	-40 to +85°C	SA630N	SOT97-1
8-Pin Plastic Small Outline (SO) package (Surface-mount)	-40 to +85°C	SA630D	SOT96-1

BLOCK DIAGRAM

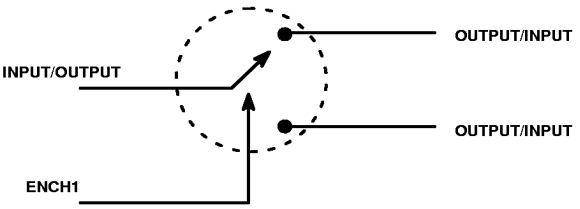


Figure 2. Block Diagram

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	RATING	UNITS
V_{DD}	Supply voltage	3.0 to 5.5V	V
T_A	Operating ambient temperature range SA Grade	-40 to +85	°C
T_J	Operating junction temperature range SA Grade	-40 to +105	°C

EQUIVALENT CIRCUIT

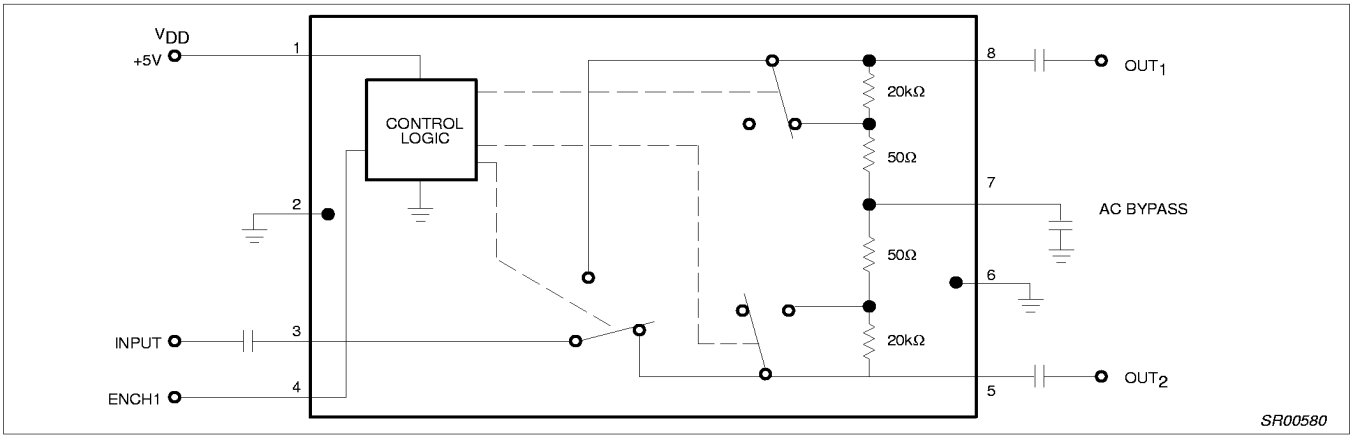


Figure 3. Equivalent Circuit

ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V_{DD}	Supply voltage	-0.5 to +5.5	V
P_D	Power dissipation, T_A = 25°C (still air)[1] 8-Pin Plastic DIP 8-Pin Plastic SO	 1160 780	 mW mW
T_{JMAX}	Maximum operating junction temperature	150	°C
P_{MAX}	Maximum power input/output	+20	dBm
T_{STG}	Storage temperature range	-65 to +150	°C

NOTES:
1. Maximum dissipation is determined by the operating ambient temperature and the thermal resistance, θ_{JA}:
   8-Pin DIP: θ_{JA} = 108°C/W
   8-Pin SO: θ_{JA} = 158°C/W

DC ELECTRICAL CHARACTERISTICS

V_{DD} = +5V, T_A = 25°C; unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			SA630			
			MIN	TYP	MAX	
I_{DD}	Supply current		40	170	300	µA
V_T	TTL/CMOS logic threshold voltage[1]		1.1	1.25	1.4	V
V_{IH}	Logic 1 level	Enable channel 1	2.0		V_{DD}	V
V_{IL}	Logic 0 level	Enable channel 2	-0.3		0.8	V
I_{IL}	ENCH1 input current	ENCH1 = 0.4V	-1	0	1	µA
I_{IH}	ENCH1 input current	ENCH1 = 2.4V	-1	0	1	µA

NOTE:
1. The ENCH1 input must be connected to a valid Logic Level for proper operation of the SA630.

AC ELECTRICAL CHARACTERISTICS[1] - D PACKAGE

V_{DD} = +5V, T_A = 25°C; unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			SA630			
			MIN	TYP	MAX	
S_{21}, S_{12}	Insertion loss (ON channel)	DC - 100MHz 500MHz 900MHz		1 1.4 2	 2.8	dB
S_{21}, S_{12}	Isolation (OFF channel)[2]	10MHz 100MHz 500MHz 900MHz	70 24	80 60 50 30		dB
S_{11}, S_{22}	Return loss (ON channel)	DC - 400MHz 900MHz		20 12		dB
S_{11}, S_{22}	Return loss (OFF channel)	DC - 400MHz 900MHz		17 13		dB
t_D	Switching speed (on-off delay)	50% TTL to 90/10% RF		20		ns
t_r, t_f	Switching speeds (on-off rise/fall time)	90%/10% to 10%/90% RF		5		ns
	Switching transients			165		mV_{P-P}
P_{-1dB}	1dB gain compression	DC - 1GHz		+18		dBm
IP_3	Third-order intermodulation intercept	100MHz		+33		dBm
IP_2	Second-order intermodulation intercept	100MHz		+52		dBm
NF	Noise figure (Z_O = 50Ω)	100MHz 900MHz		1.0 2.0		dB

NOTE:
1. All measurements include the effects of the D package SA630 Evaluation Board (see Figure 4B). Measurement system impedance is 50Ω.
2. The placement of the AC bypass capacitor is critical to achieve these specifications. See the applications section for more details.

AC ELECTRICAL CHARACTERISTICS[1] - N PACKAGE

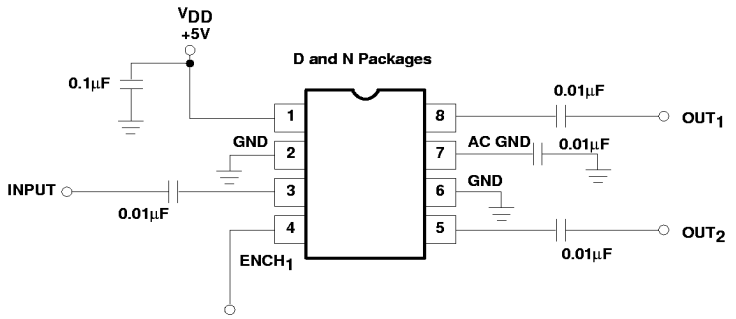
V_{DD} = +5V, T_A = 25°C; all other characteristics similar to the D-Package, unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			SA630			
			MIN	TYP	MAX	
S_{21}, S_{12}	Insertion loss (ON channel)	DC - 100MHz 500MHz 900MHz		1 1.4 2.5		dB
S_{21}, S_{12}	Isolation (OFF channel)	10MHz 100MHz 500MHz 900MHz	58	68 50 37 15		dB
NF	Noise figure (Z_O = 50Ω)	100MHz 900MHz		1.0 2.5		dB

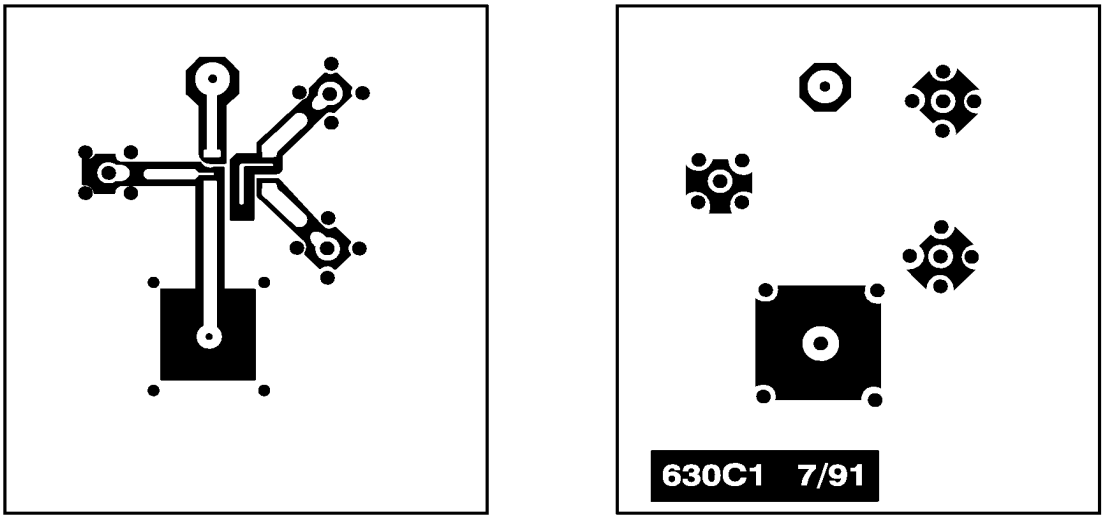
NOTE:
1. All measurements include the effects of the N package SA630 Evaluation Board (see Figure 4C). Measurement system impedance is 50Ω.

APPLICATIONS

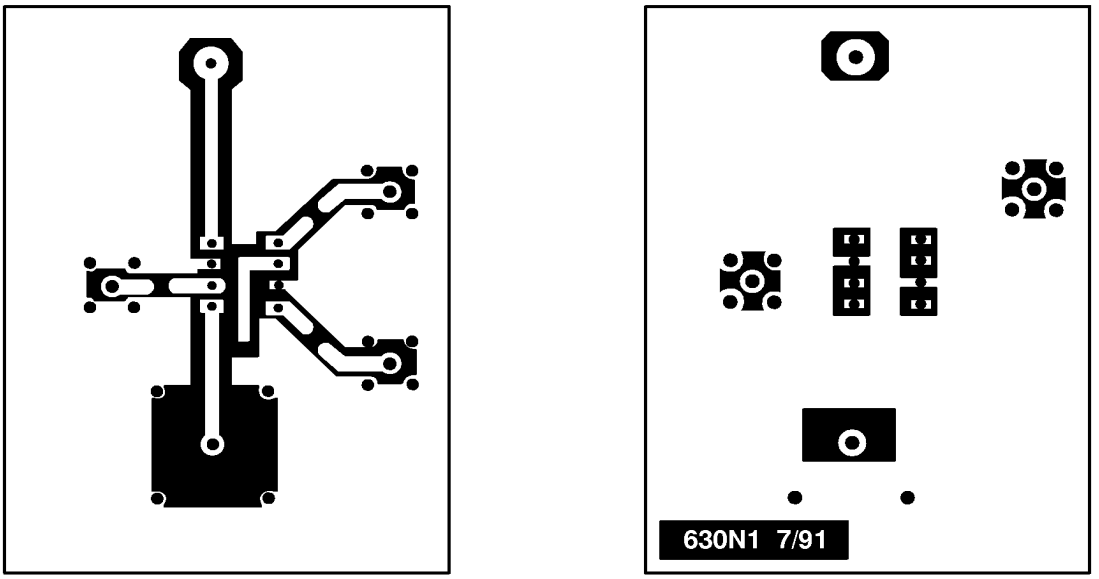
The typical applications schematic and printed circuit board layout of the SA630 evaluation board is shown in Figure 4. The layout of the board is simple, but a few cautions need to be observed. The input and output traces should be 50Ω. The placement of the AC bypass capacitor is *extremely critical* if a symmetric isolation between the two channels is desired. The trace from Pin 7 should be drawn back towards the package and then be routed downwards. The capacitor should be placed straight down as close to the device as practical. For better isolation between the two channels at higher frequencies, it is also advisable to run the two output/input traces at an angle. This also minimizes any inductive coupling between the two traces. The power supply bypass capacitor should be placed close to the device. Figure 10 shows the frequency response of the SA630. The loss matching between the two channels is excellent to 1.2GHz as shown in Figure 13.



a. Evaluation Board Schematic



b. 630 D-Package Board Layout



c. 630 N-Package Board Layout

SR00581

Figure 4. Board and Package Graphics

The isolation and matching of the two channels over frequency is shown in Figures 15 and 17, respectively.

The SA630 is a very versatile part and can be used in many applications. Figure 5 shows a block diagram of a typical Digital RF transceiver front-end. In this application the SA630 replaces the duplexer which is typically very bulky and lossy. Due to the low power consumption of the device, it is ideally suited for handheld applications such as in CT2 cordless telephones. The SA630 can also be used to generate Amplitude Shift Keying (ASK) or On-Off Keying (OOK) and Frequency Shift Keying (FSK) signals for digital RF communications systems. Block diagrams for these applications are shown in Figures 6 and 7, respectively.

For applications that require a higher isolation at 1GHz than obtained from a single SA630, several SA630s can be cascaded as shown in Figure 8. The cascaded configuration will have a higher loss but greater than 35dB of isolation at 1GHz and greater than 65dB @ 500MHz can be obtained from this configuration. By modifying the enable control, an RF multiplexer/ de-multiplexer or antenna selector can be constructed. The simplicity of SA630 coupled with its ease of use and high performance lends itself to many innovative applications.

The SA630 switch terminates the OFF channel in 50Ω. The 50Ω resistor is internal and is in series with the external AC bypass capacitor. Matching to impedances other than 50Ω can be achieved by adding a resistor in series with the AC bypass capacitor (e.g., 25Ω additional to match to a 75Ω environment).

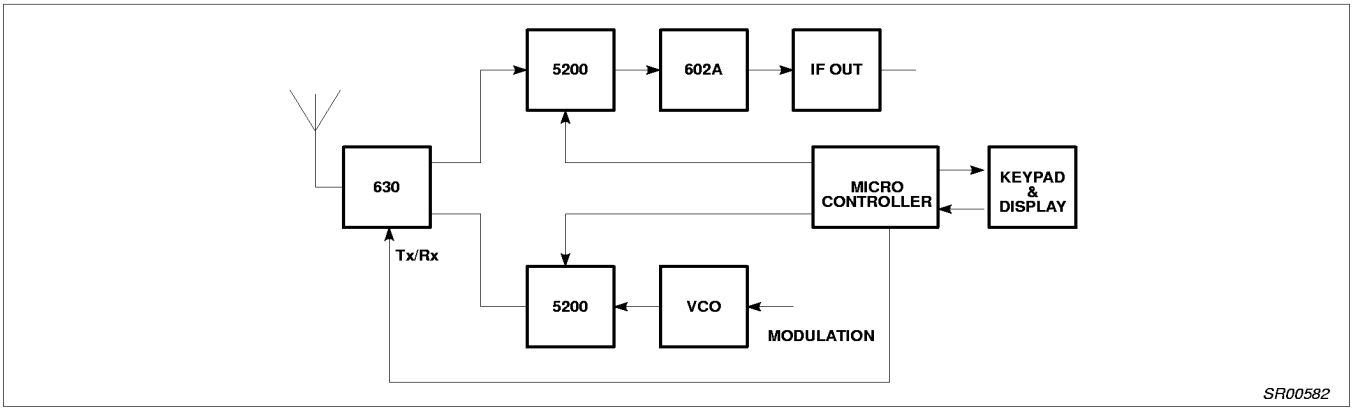


Figure 5. A Typical TDMA/Digital RF Transceiver System Front-End

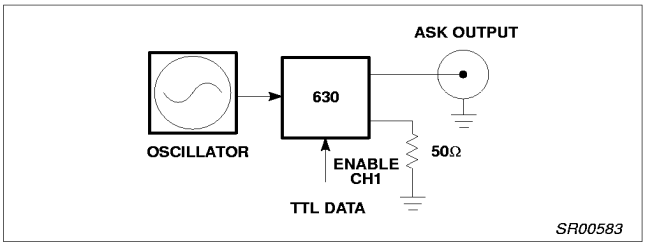


Figure 6. Amplitude Shift Keying (ASK) Generator

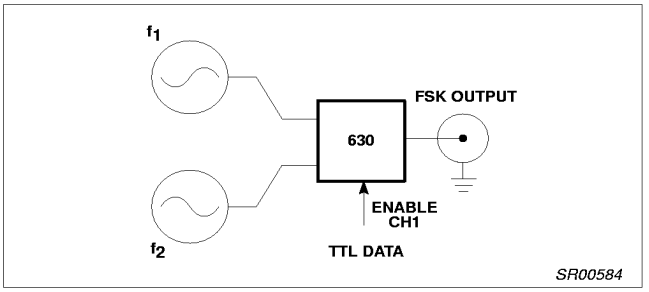


Figure 7. Frequency Shift Keying (FSK) Gnerator

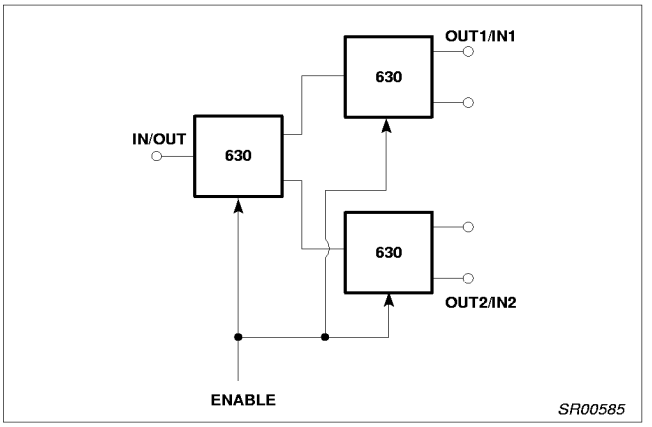


Figure 8.

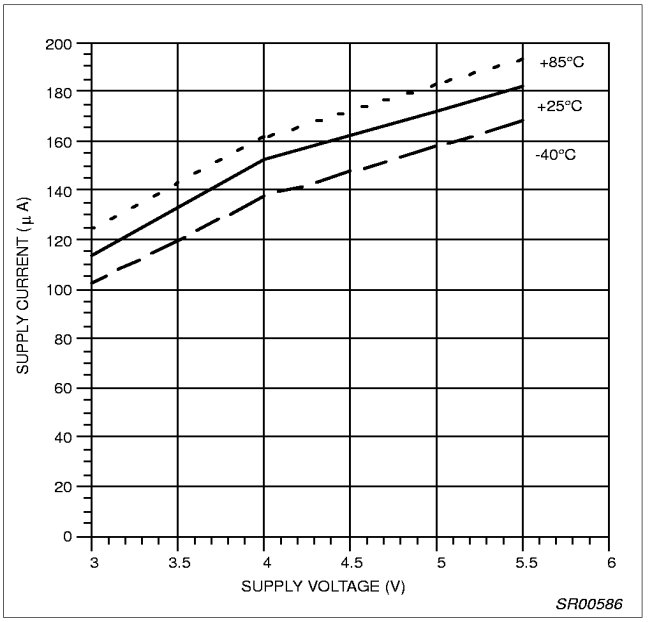


Figure 9. Supply Current vs. V_{DD} and Temperature

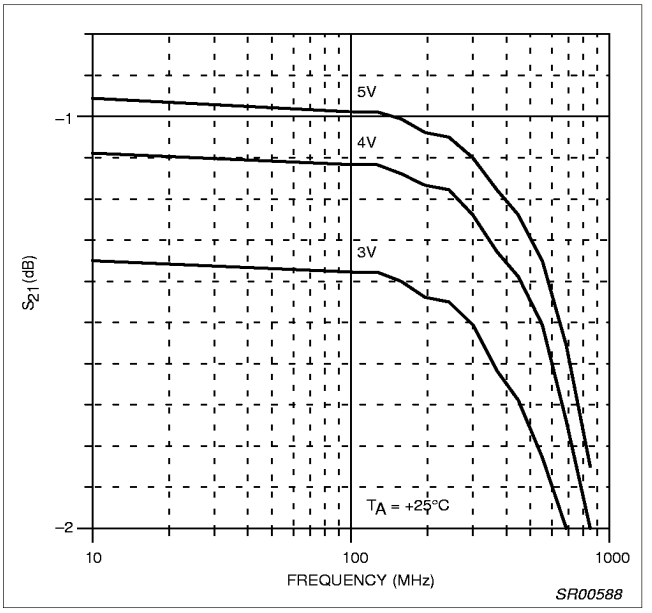


Figure 11. Loss vs. Frequency and V_{DD} for D-Package-Expanded Detail-

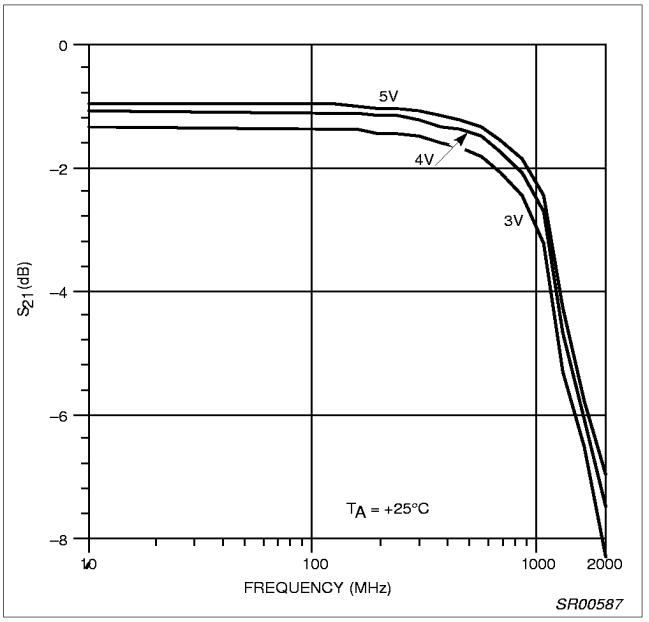


Figure 10. Loss vs. Frequency and V_{DD} for D-Package

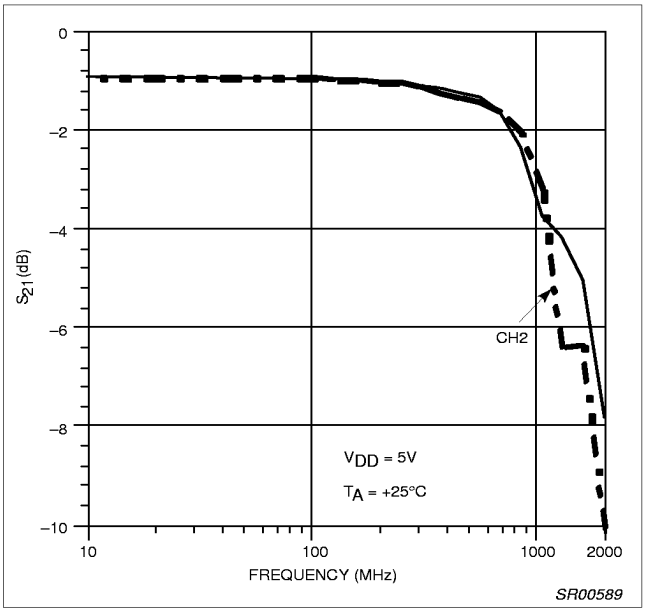


Figure 12. Loss Matching vs. Frequency for N-Package (DIP)

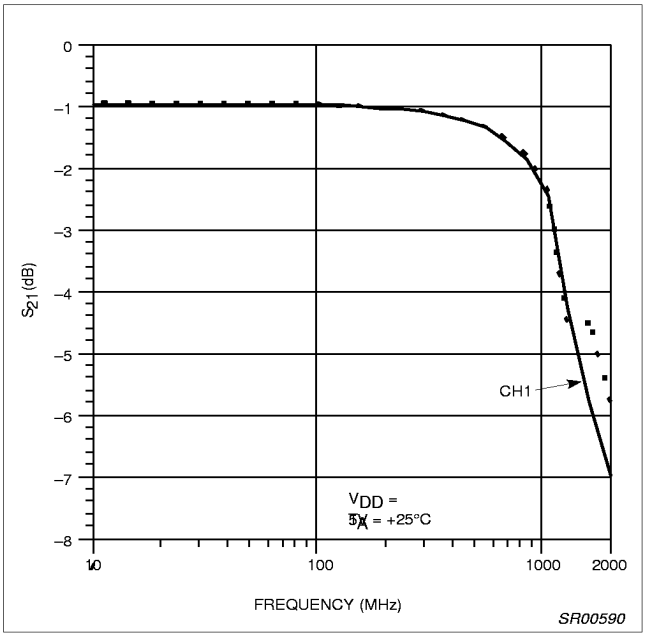


Figure 13. Loss Matching vs. Frequency; CH1 vs. CH2 for D-Pakage

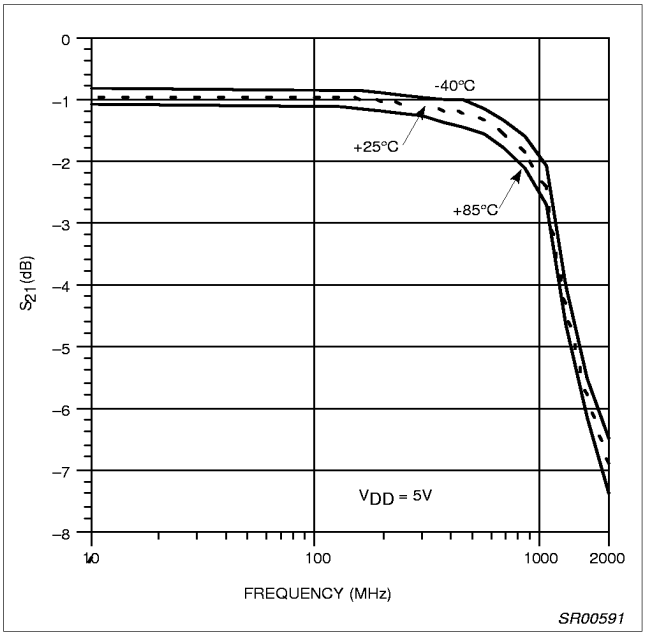


Figure 14. Loss vs. Frequency and Temperature for D-Package

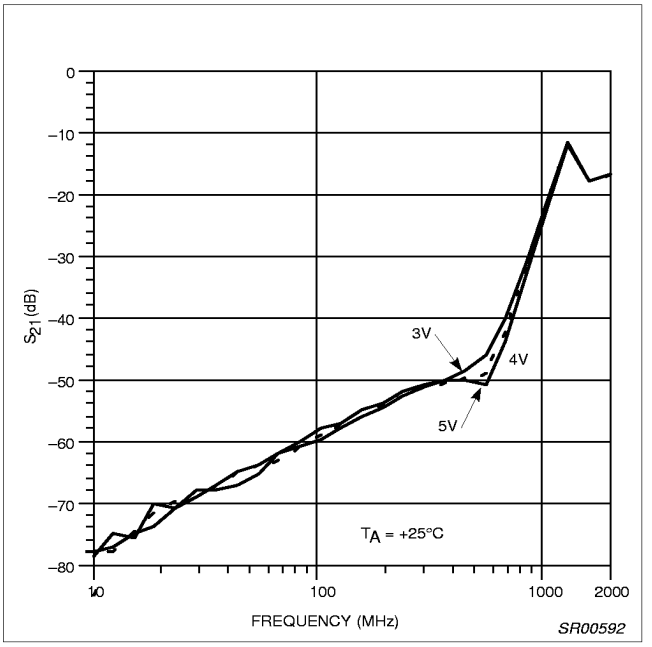


Figure 15. Isolation vs. Frequency and V_{DD} for D-Package

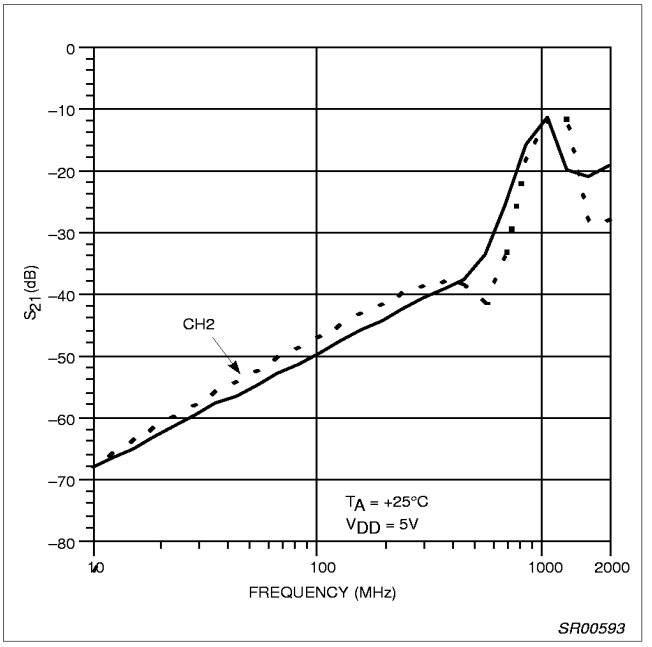


Figure 16. Isolation Matching vs. Frequency for N-Package (DIP)

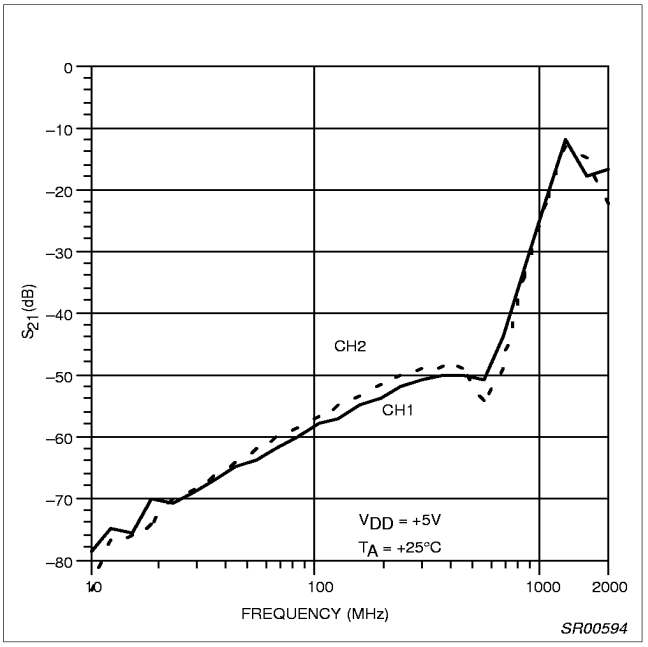


Figure 17. Isolation Matching vs. Frequency; CH1 vs. CH2 for D-Package

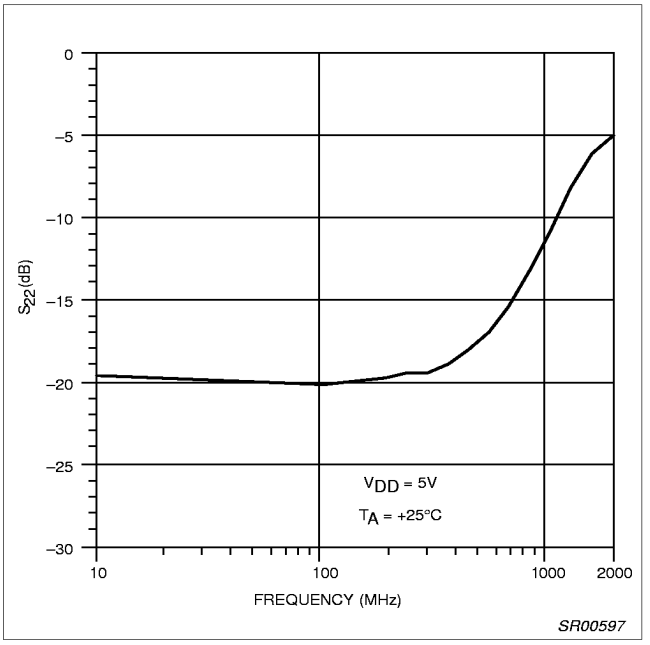


Figure 19. Output Match On-Channel vs. Frequency

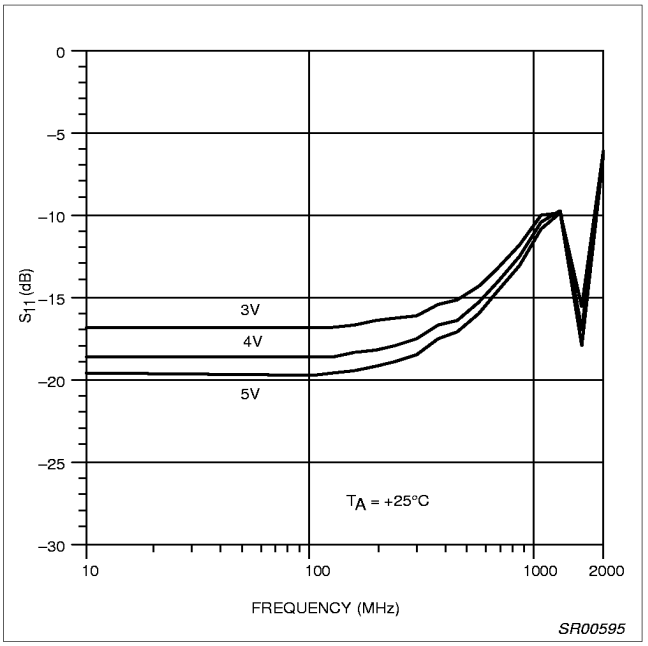


Figure 18. Input Match On-Channel vs. Frequency and V_{DD}

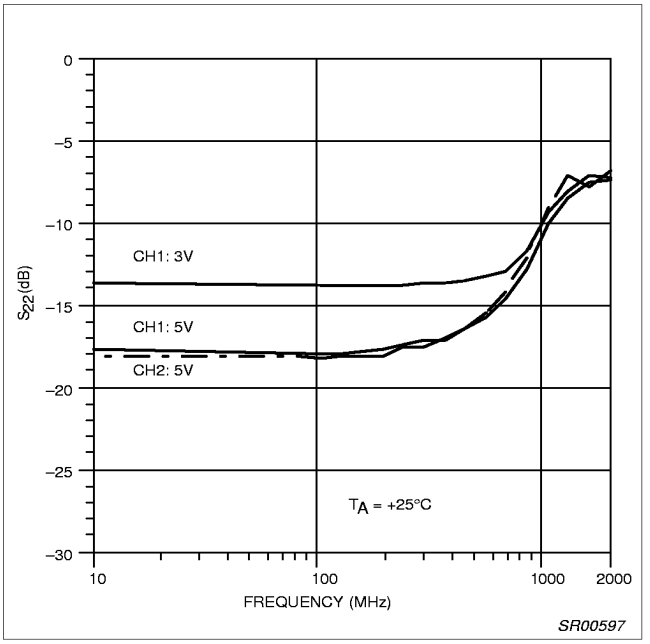


Figure 20. OFF-Channel Match vs. Frequency and V_{DD}

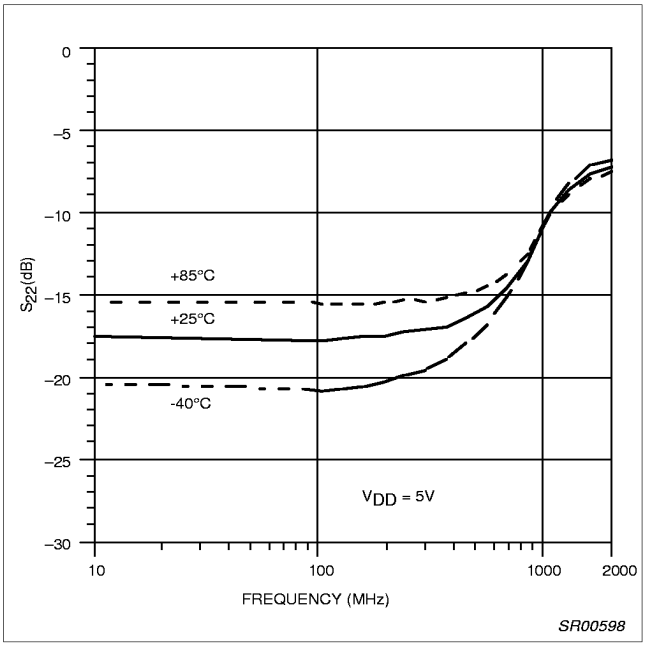


Figure 21. OFF Channel Match vs. Frequency and Temperature

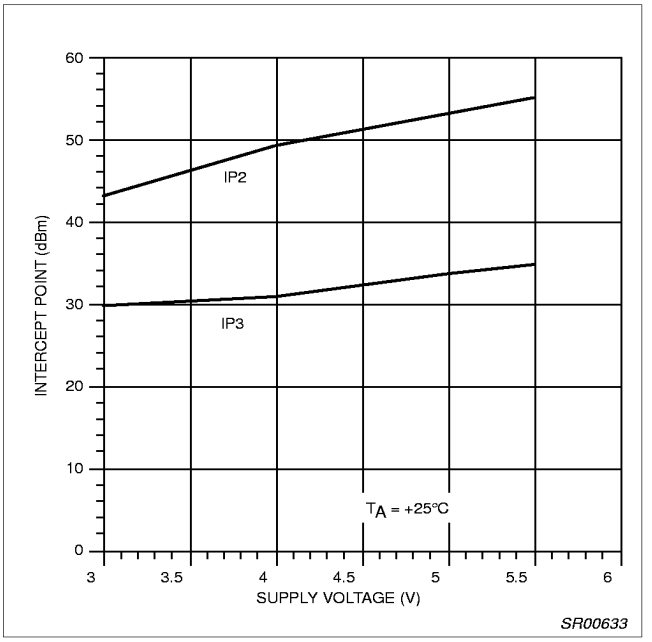


Figure 23. Intercept Points vs.V_{DD}

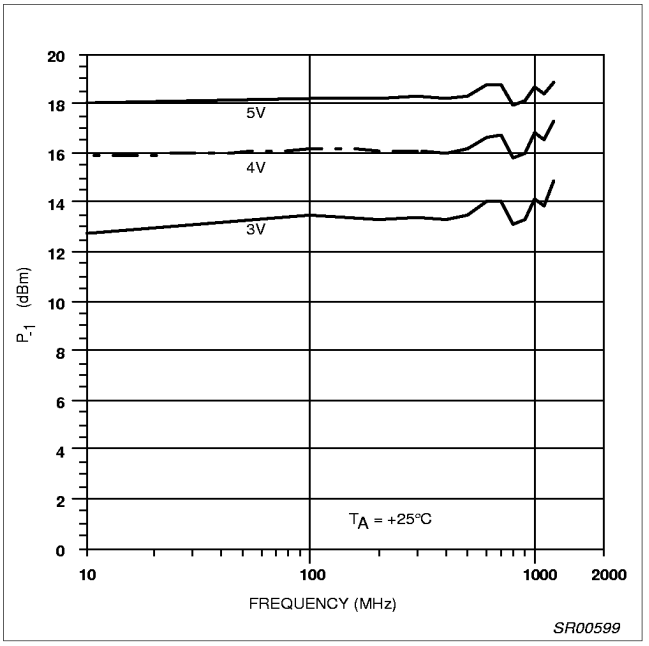


Figure 22. P_{-1} dB vs. Frequency and V_{DD}

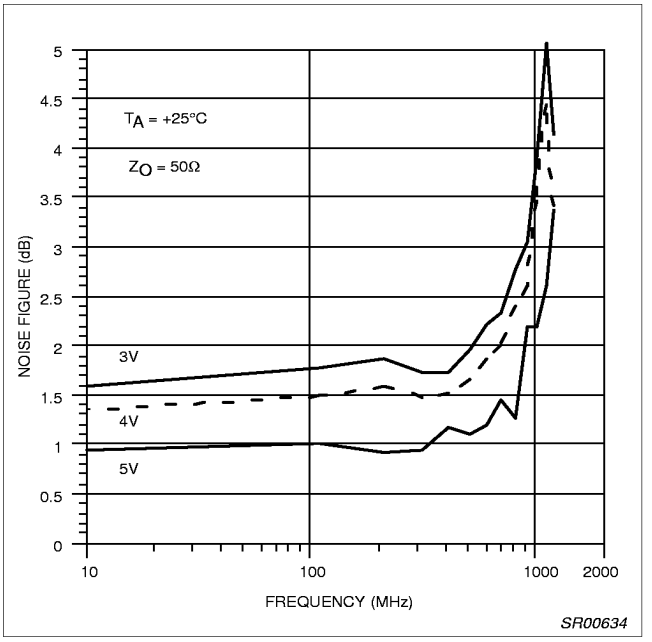


Figure 24. Noise Figure vs. Frequency and V_{DD} for D-Package

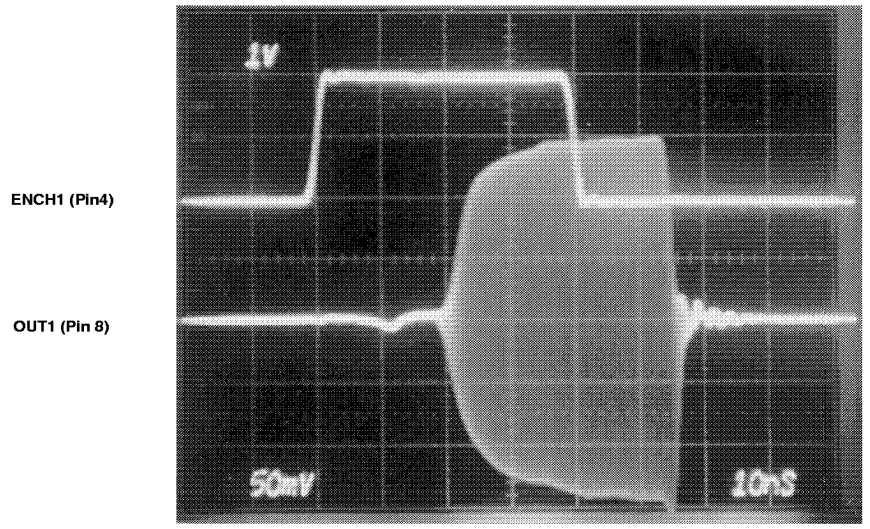
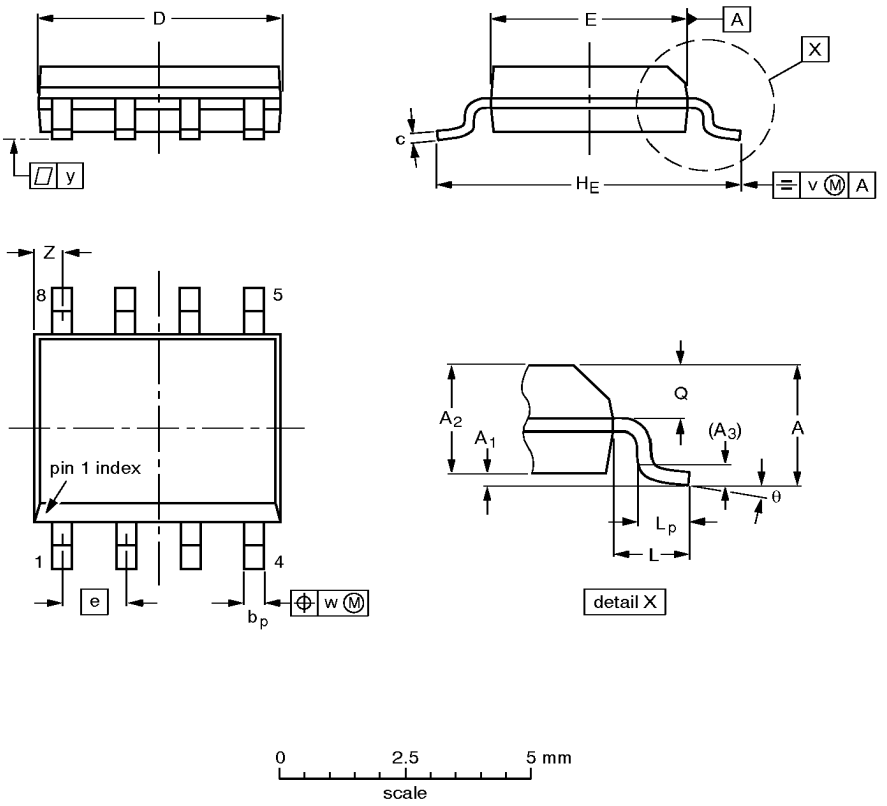


Figure 25. Switching Speed; f_{IN} = 100MHz at -6dBm, V_{DD} = 5V

SO8: plastic small outline package; 8 leads; body width 3.9mm SOT96-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

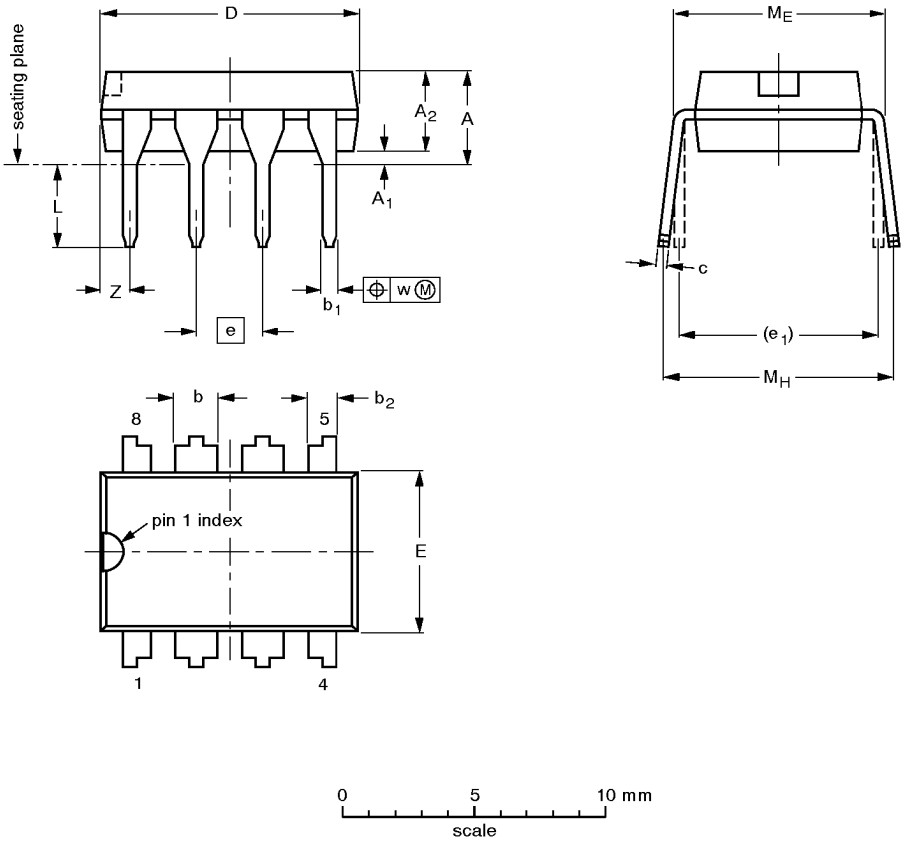
UNIT	A max.	A_1	A_2	A_3	b_p	c	$D^{(1)}$	$E^{(2)}$	e	H_E	L	L_p	Q	v	w	y	$Z^{(1)}$	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	5.0 4.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8° 0°
inches	0.069	0.0098 0.0039	0.057 0.049	0.01	0.019 0.014	0.0098 0.0075	0.20 0.19	0.16 0.15	0.050	0.24 0.23	0.041	0.039 0.016	0.028 0.024	0.01	0.01	0.004	0.028 0.012	

Notes

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
2. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT96-1	076E03S	MS-012AA				~~92-11-17~~ 95-02-04

DIP8: plastic dual in-line package; 8 leads (300 mil) SOT97-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A_1 min.	A_2 max.	b	b_1	b_2	c	D (1)	E (1)	e	e_1	L	M_E	M_H	w	Z (1) max.
mm	4.2	0.51	3.2	1.73 1.14	0.53 0.38	1.07 0.89	0.36 0.23	9.8 9.2	6.48 6.20	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	1.15
inches	0.17	0.020	0.13	0.068 0.045	0.021 0.015	0.042 0.035	0.014 0.009	0.39 0.36	0.26 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.045

Note

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT97-1	050G01	MO-001AN				~~92-11-17~~ 95-02-04